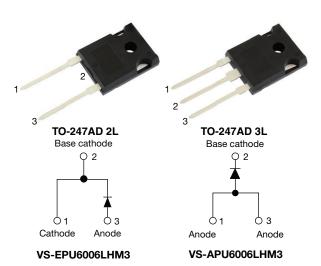


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Vishay Semiconductors

Ultrafast Soft Recovery Diode, 60 A FRED Pt®



PRIMARY CHARACTERISTICS						
I _{F(AV)}	60 A					
V_{R}	600 V					
V _F at I _F	1.05 V					
t _{rr} typ.	32 ns					
T _J max.	175 °C					
Package	TO-247AD 2L, TO-247AD 3L					
Circuit configuration	Single					

FEATURES

- Ultrafast recovery time
- Low forward voltage drop
- 175 °C operating junction temperature
- AEC-Q101 qualified meets JESD 201 class 1 whisker test
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>



DESCRIPTION / APPLICATIONS

VS-EPU60... series are the state of the art ultrafast recovery rectifiers designed with optimized performance of forward voltage drop and ultrafast recovery time.

The planar structure and the platinum doped life time control guarantee the best overall performance, ruggedness and reliability characteristics.

These devices are intended for use in the output rectification stage of SMPS, welding, UPS, DC/DC converters as well as freewheeling diodes in low voltage inverters and chopper motor drives.

Their extremely optimized stored charge and low recovery current minimize the switching losses and reduce over dissipation in the switching element and snubbers.

ABSOLUTE MAXIMUM RATINGS							
PARAMETER	SYMBOL	TEST CONDITIONS	MAX.	UNITS			
Repetitive peak reverse voltage	V_{RRM}		600	V			
Average rectified forward current in DC	I _{F(AV)}	T _C = 116 °C	60	Α			
Single pulse forward current	I _{FSM}	$T_C = 25$ °C, $t_p = 8.3$ ms; half sine wave	600	A			
Operating junction and storage temperatures	T _J , T _{Stg}		-55 to +175	°C			

ELECTRICAL SPECIFICATIONS (T _J = 25 °C unless otherwise specified)						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Breakdown voltage, blocking voltage	V _{BR} , V _R	I _R = 100 μA	600	-	-	
		I _F = 60 A	-	1.2	1.5	V
Forward voltage	V_{F}	I _F = 60 A, T _J = 125 °C	-	1.1	1.3	
		I _F = 60 A, T _J = 175 °C	-	1.05	1.2	
Reverse leakage current		V _R = V _R rated	-	0.2	30	
	I _R	T _J = 150 °C, V _R = V _R rated	-	-	200	μΑ
Junction capacitance	C _T	V _R = 600 V	-	38	-	pF



VS-EPU6006LHN3, VS-APU6006LHN3

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DYNAMIC RECOVERY CHARACTERISTICS (T _J = 25 °C unless otherwise specified)								
PARAMETER	SYMBOL	TEST CO	NDITIONS	MIN.	TYP.	MAX.	UNITS	
		$I_F = 1 A, di_F/dt = 20$	$I_F = 1 \text{ A, di}_F/\text{dt} = 200 \text{ A/}\mu\text{s, V}_R = 30 \text{ V}$		32	-		
Reverse recovery time	t _{rr}	T _J = 25 °C		=	110	-	ns A	
		T _J = 125 °C	I _F = 60 A di _F /dt = 200 A/µs V _R = 200 V	=	200	-		
Peak recovery current	I _{RRM}	T _J = 25 °C		=	10	-		
		T _J = 125 °C		-	19	-		
Reverse recovery charge	0	T _J = 25 °C		=	530	-	nC	
	Q_{rr}	T _J = 125 °C		-	1900	-		

THERMAL - MECHANICAL SPECIFICATIONS							
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS	
Maximum junction and storage temperature range	T _J , T _{Stg}		-55	-	175	°C	
Thermal resistance, junction to case	R _{thJC}		-	-	0.65		
Thermal resistance, junction to ambient	R _{thJA}	Typical socket mount	-	-	70	°C/W	
Thermal resistance, case to heat sink	R _{thCS}	Mounting surface, flat, smooth and greased	-	0.5	-		
Woiselpt			=	6	-	g	
Weight			-	0.21	-	oz.	
Mounting torque			6 (5)	=	1.2 (10)	kgf. cm (lbf · in)	
		Case style: TO-247AD 2L		EPU6	006LH		
Marking device		Case style: TO-247AD 3L		APU6006LH			

150 °C

125 °C

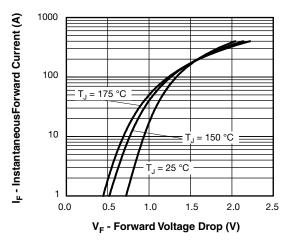
175 °C

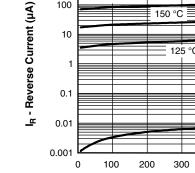
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25 °C

500

600





1000

100

10

Fig. 1 - Typical Forward Voltage Drop Characteristics

V_R - Reverse Voltage (V) Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

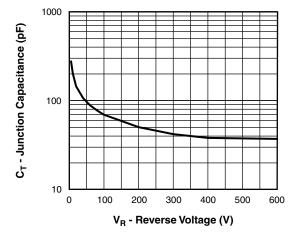


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

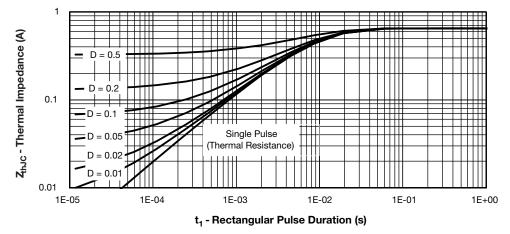
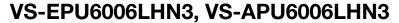


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics





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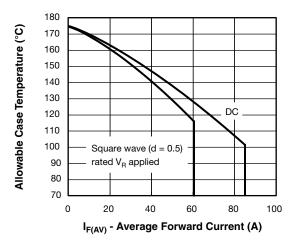


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current

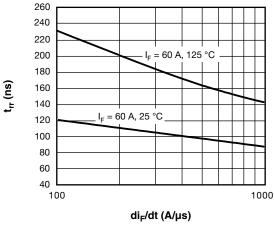


Fig. 7 - Typical Reverse Recovery Time vs. di_F/dt

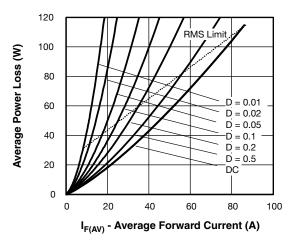


Fig. 6 - Forward Power Loss Characteristics

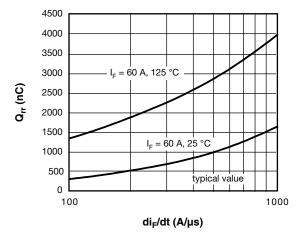
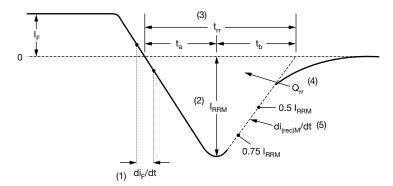


Fig. 8 - Typical Stored Charge vs. di_F/dt

Note

(1) Formula used: $T_C = T_J - (Pd + Pd_{REV}) \times R_{th,JC}$; $Pd = forward power loss = I_{F(AV)} \times V_{FM} at (I_{F(AV)}/D)$ (see fig. 6); $Pd_{REV} = inverse power loss = V_{R1} \times I_R (1 - D)$; I_R at $V_{R1} = 80 \%$ rated V_R

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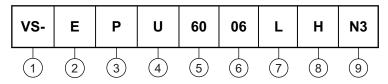


- (1) di_E/dt rate of change of current through zero crossing
- (4) Q_{rr} area under curve defined by t_{rr} and I_{RRM}
- (2) I_{RRM} peak reverse recovery current
- $Q_{rr} = \frac{t_{rr} x I_{RRM}}{2}$
- (3) t_{rr} reverse recovery time measured from zero crossing point of negative going I_F to point where a line passing through 0.75 I_{RRM} and 0.50 I_{RRM} extrapolated to zero current.
- (5) $di_{(rec)M}/dt$ peak rate of change of current during th portion of tr

Fig. 9 - Reverse Recovery Waveform and Definitions

ORDERING INFORMATION TABLE

Device code



- Vishay Semiconductors product
- Circuit configuration:
 - E = single diode 2 pins
 - A = single diode 3 pins
- P = TO-247
- U = ultrafast recovery time
- Current code (60 = 60 A)
- Voltage code (06 = 600 V)
- L = long lead
- H = AEC-Q101 qualified
- Environmental digit:

N3 = halogen-free, RoHS-compliant, and totally lead (Pb)-free

ORDERING INFORMATION (Example)						
PREFERRED P/N	QUANTITY PER TUBE	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION			
VS-EPU6006LHN3	25	500	Antistatic plastic tube			
VS-APU6006LHN3	25	500	Antistatic plastic tube			

LINKS TO RELATED DOCUMENTS					
Dimensions	TO-247AD 2L	www.vishay.com/doc?95536			
Differsions	TO-247AD 3L	www.vishay.com/doc?95626			
Dout moulcing information	TO-247AD 2L	www.vishay.com/doc?95648			
Part marking information	TO-247AD 3L	www.vishay.com/doc?95007			

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TO-247AD 2L

DIMENSIONS in millimeters and inches



View B

SYMBOL	MILLIN	MILLIMETERS		INCHES	
STMBOL	MIN.	MAX.	MIN.	MAX.	NOTES
Α	4.65	5.31	0.183	0.209	
A1	2.21	2.59	0.087	0.102	
A2	1.50	2.49	0.059	0.098	
b	0.99	1.40	0.039	0.055	
b1	0.99	1.35	0.039	0.053	
b2	1.65	2.39	0.065	0.094	
b3	1.65	2.34	0.065	0.092	
С	0.38	0.89	0.015	0.035	
c1	0.38	0.84	0.015	0.033	
D	19.71	20.70	0.776	0.815	3
D1	13.08	-	0.515	-	4
D2	0.51	1.35	0.020	0.053	

Section C - C, D - D

SYMBOL	MILLIN	IETERS	INC	HES	NOTES
STWIDOL	MIN.	MAX.	MIN.	MAX.	NOTES
Е	15.29	15.87	0.602	0.625	3
E1	13.46	-	0.53	-	
е	5.46	BSC	0.215	BSC	
ØK	0.2	0.254)10	
L	19.81	20.32	0.780	0.800	
L1	3.71	4.29	0.146	0.169	
ØΡ	3.56	3.66	0.14	0.144	
Ø P1	-	6.98	-	0.275	
Q	5.31	5.69	0.209	0.224	
R	4.52	5.49	0.178	0.216	
S	5.51 BSC		0.217	'BSC	
		•			

Notes

- (1) Dimensioning and tolerancing per ASME Y14.5M-1994
- (2) Contour of slot optional
- (3) Dimension D and E do not include mold flash. These dimensions are measured at the outermost extremes of the plastic body
- (4) Thermal pad contour optional with dimensions D1 and E1
- (5) Lead finish uncontrolled in L1
- (6) Ø P to have a maximum draft angle of 1.5 to the top of the part with a maximum hole diameter of 3.91 mm (0.154")
- (7) Outline conforms to JEDEC® outline TO-247 with exception of dimension A min., D, E min., Q min., S, and note 4



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